



NPN POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/518

Devices Qualified Level

2N3766 2N3767

JAN JANTX JANTXV

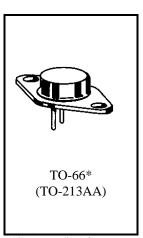
MAXIMUM RATINGS

Ratings	Symbol	2N3766	2N3767	Units
Collector-Emitter Voltage	V_{CEO}	60	80	Vdc
Collector-Base Voltage	V_{CBO}	80 100		Vdc
Emitter-Base Voltage	V_{EBO}	6.0		Vdc
Base Current	I_{B}	2.0		Adc
Collector Current	I_{C}	4.0		Adc
Total Power Dissipation @ $T_C = +25^0 C^{(1)}$	P_{T}	25		W
Operating & Storage Temperature Range	Top, Tstg	-65 to +200		⁰ C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	7.0	⁰ C/W

¹⁾ Derate linearly 143 mW/ $^{\circ}$ C between $T_{C} = +25^{\circ}$ C and $T_{C} = +200^{\circ}$ C



*See Appendix A for Package Outline

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}$ C unless otherwise noted)

Characteristi	cs	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage					
$I_C = 100 \text{ mAdc}$	2N3766 2N3767	$V_{(BR)CEO}$	60 80		Vdc
Collector-Emitter Cutoff Current					
$V_{CE} = 60 \text{ Vdc}$	2N3766	I_{CEO}		500	μAdc
$V_{CE} = 80 \text{ Vdc}$	2N3767			500	
Collector-Emitter Cutoff Current					
$V_{CE} = 80 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$	2N3766	I_{CEX}		10	μAdc
$V_{CE} = 100 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$	2N3767			10	
Collector-Base Cutoff Current					
$V_{CB} = 80 \text{ Vdc}$	2N3766	I_{CBO}		10	μAdc
$V_{CB} = 100 \text{ Vdc}$	2N3767			10	
Emitter-Base Cutoff Current		Ī	T		μAdc
$V_{EB} = 6.0 \text{ Vdc}$		I_{EBO}		500	μΑαс

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2N3766, 2N3767 JAN SERIES

ELECTRICAL CHARACTERISTICS (con't)

Characteristics	Symbol	Min.	Max.	Unit
ON CHARACTERISTICS (2)				
Forward-Current Transfer Ratio				
$I_C = 50 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$	1.	30		
$I_C = 500 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$	$h_{ m FE}$	40	160	
$I_C = 1.0 \text{ Adc}, V_{CE} = 10 \text{ Vdc}$		20		
Collector-Emitter Saturation Voltage			2.5	
$I_C = 1.0 \text{ Adc}, I_B = 0.1 \text{ Adc}$	$V_{CE(sat)}$		2.5 1.0	Vdc
$I_C = 0.5 \text{ Adc}, I_B = 0.05 \text{ Adc}$			1.0	
Base-Emitter Voltage	3.7		1.5	Vdc
$I_C = 1.0 \text{ Adc}, V_{CE} = 10 \text{ Vdc}$	V _{BE(on)}			
DYNAMIC CHARACTERISTICS				
Magnitude of Common Emitter Small-Signal Short-Circuit		1.0		
Forward Current Transfer Ratio	h _{fe}		8.0	
$I_C = 500 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 10 \text{ MHz}$		1.0		
Output Capacitance	C		50	пE
$V_{CB} = 10 \text{ Vdc}, I_E = 0, 0.1 \text{ MHz} \le f \le 1.0 \text{ MHz}$	C_{obo}		30	pF
SWITCHING CHARACTERISTICS				
Turn-On Time	^t on		0.25	Ша
$V_{CC} = 30 \text{ Vdc}; I_C = 0.5 \text{ Adc}; I_B = 0.05 \text{ Adc}$	OII		0.23	μs
Turn-Off Time	toff		2.5	Ша
$V_{CC} = 30 \text{ Vdc}; I_C = 0.5 \text{ Adc}; I_B = I_B = 0.05 \text{ Adc}$	OH		2.3	μs

SAFE OPERATING AREA

DC Tests

 $T_C = +25^{\circ}C$, 1 Cycle, t = 1.0 s

Test 1

 $V_{CE} = 6.25 \text{ Vdc}, I_{C} = 4.0 \text{ Adc}$

Test 2

 $V_{CE} = 20 \text{ Vdc}, I_{C} = 1.25 \text{ Adc}$

Test 3

 $V_{CE} = 50 \text{ Vdc}, I_{C} = 150 \text{ mAdc}$ 2N3766 $V_{CE} = 65 \text{ Vdc}, I_{C} = 150 \text{ mAdc}$ 2N3767

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⁽²⁾ Pulse Test: Pulse Width = 300μ s, Duty Cycle $\leq 2.0\%$.

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